

# AIGaAs Infrared Laser Diode

**ADL-78101TL**

6-2D-LD78-003\_Rev.03

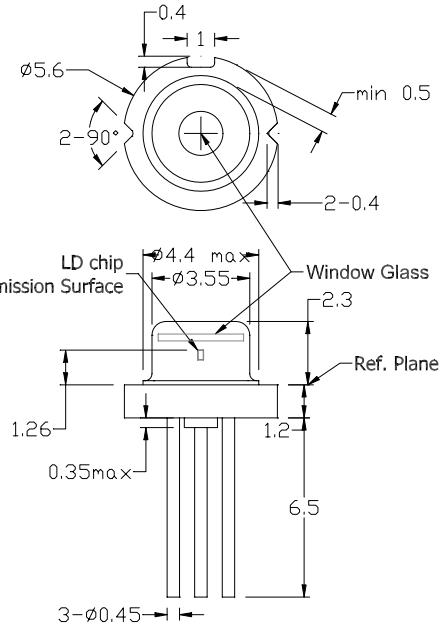
★ 780nm 10mW 60 °C Reliable Operation!

## • Features

1. Low operating current
2. High efficiency
3. Better power budget for optical design

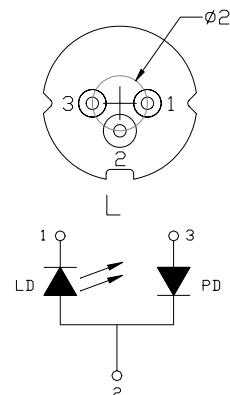
## • Applications

1. Industrial Tools



## • Absolute maximum ratings

Parameter	Symbol	Condition	Rating	Unit
Light output power	P <sub>O</sub>	CW	12	mW
Reverse voltage (LD)	V <sub>RL</sub>	-	2	V
Reverse voltage (PD)	V <sub>RD</sub>	-	30	V
Forward current (PD)	I <sub>FD</sub>	-	10	mA
Case temperature	T <sub>C</sub>	-	-10~+60	°C
Storage temperature	T <sub>S</sub>	-	-40~+85	°C



## • Electrical and optical characteristics (T<sub>c</sub>=25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Peak wavelength	λ	770	780	790	nm	P <sub>o</sub> =10mW
Threshold current	I <sub>th</sub>	-	15	25	mA	
Operating current	I <sub>op</sub>	-	30	40	mA	P <sub>o</sub> =10mW
Operating voltage	V <sub>op</sub>	-	1.9	2.2	V	P <sub>o</sub> =10mW
Differential efficiency	η	0.4	0.6	0.8	mW/mA	P <sub>o</sub> =7-10mW
Monitor current	I <sub>m</sub>	0.2	0.6	1.2	mA	P <sub>o</sub> =10mW, V <sub>RD</sub> =5V
Parallel divergence angle	θ <sub>  </sub>	7	11	15	deg	
Perpendicular divergence angle	θ <sub>⊥</sub>	24	28	32	deg	
Parallel FFP deviation angle	Δθ <sub>  </sub>	-2	0	+2	deg	P <sub>o</sub> =10mW
Perpendicular FFP deviation angle	Δθ <sub>⊥</sub>	-3	0	+3	deg	
Emission point accuracy	Δx Δy Δz	-80	0	+80	μm	

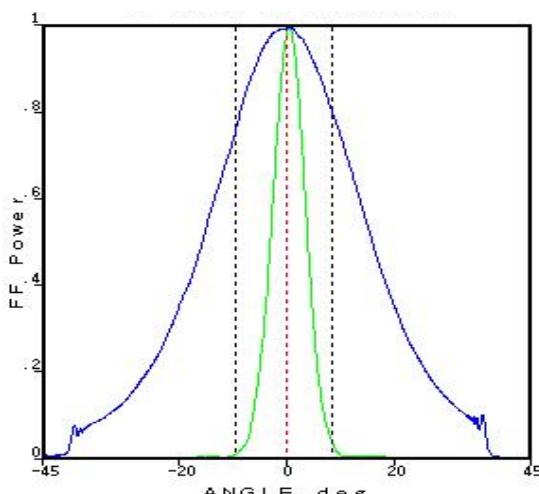
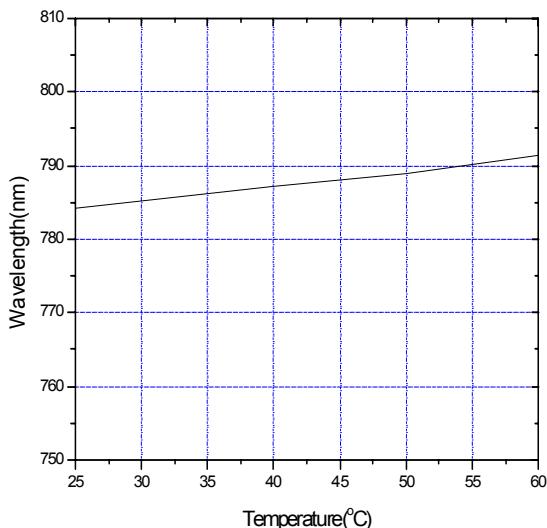
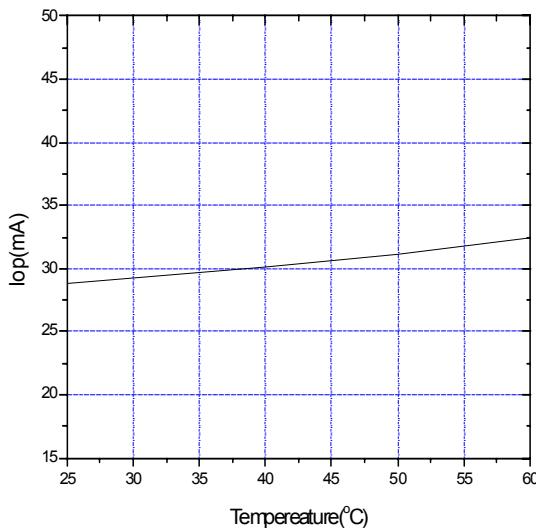
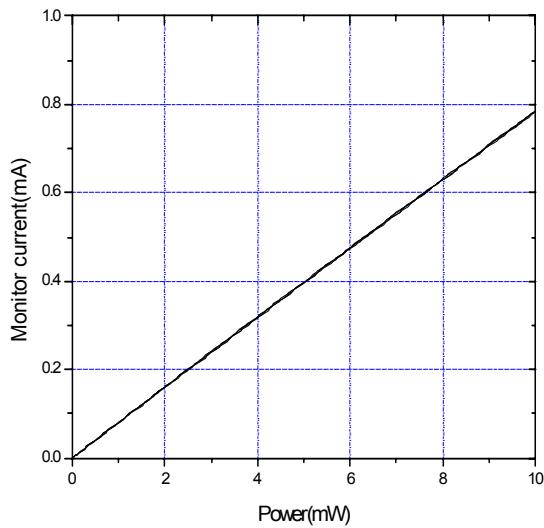
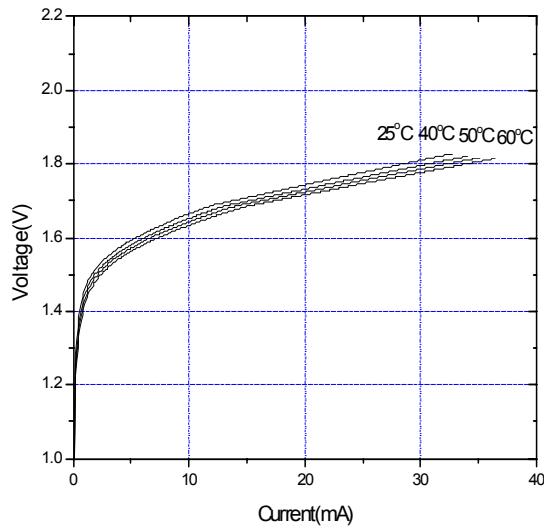
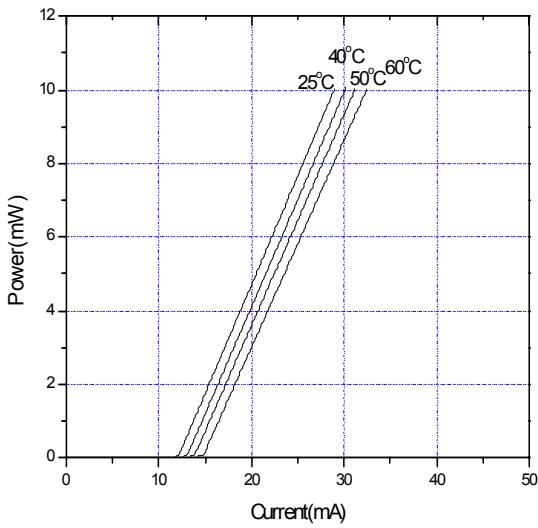
### • Precautions

- \* Do not operate the device above maximum ratings. Doing so may cause unexpected and permanent damage to the device.
- \* Take precautions to avoid electrostatic discharge and/or momentary power spikes. A change in the characteristics of the laser or premature failure may result.
- \* Proper heat sinking of the device assures stability and lifetime. Always ensure that maximum operating temperatures are not exceeded.
- \* Observing visible or invisible laser beams with the human eye directly, or indirectly, can cause permanent damage. Use a camera to observe the laser.
- \* No laser device should be used in any application or situation where life or property is at risk in event of device failure.
- \* Specifications are subject to change without notice. Ensure that you have the latest specification by contacting us prior to purchase or use of the product.

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**Arima**  
**LASERS**